

	Application No.	Applicant(s)
Notice of Allowability	10/698,558	DRIES ET AL.
	Examiner	Art Unit
	Tony Lu	2878
	Tony Lu	2070
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this apportant or other appropriate communication GHTS. This application is subject to	plication. If not included will be mailed in due course. THIS
1. This communication is responsive to <u>amendment filed on 1</u>	<u>1/09/2006</u> .	
2. The allowed claim(s) is/are <u>1-6,8-17 and 19-22</u> .		
3. Acknowledgment is made of a claim for foreign priority ur a) All b) Some* c) None of the:		
1. Certified copies of the priority documents have been received.		
2. Certified copies of the priority documents have been received in Application No		
3. Copies of the certified copies of the priority documents have been received in this national stage application from the		
International Bureau (PCT Rule 17.2(a)). * Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		
4. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.		
5. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.		
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached		
1) 🗌 hereto or 2) 🔲 to Paper No./Mail Date		
(b) ☐ including changes required by the attached Examiner' Paper No./Mail Date	s Amendment / Comment or in the C	Office action of
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written on the drawi he header according to 37 CFR 1.121(ngs in the front (not the back) of d).
 DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL. 		
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Attachment(s) 1. ☐ Notice of References Cited (PTO-892)	5. Notice of Informal F	Patent Application (PTO-152)
2. \square Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ⊠ Interview Summary Paper No./Mail Da	
3. Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date		
Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. 🛭 Examiner's Stateme	ent of Reasons for Allowance
of Diological Material	9.	George Lyc

U.S. Patent and Trademark Office PTOL-37 (Rev. 7-05)

Notice of Allowability

Georgia Epp/ Supervisory Patent Examiner Technology Center 2800 Part of Paper No./Mail Date 03162006

Art Unit: 2878

DETAILED ACTION

EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Peter Malen on 3/17/2006.

The application has been amended as follows:

Claim 1 should read:

1. A fiber-optic transceiver for use in optical communications where the fiber-optic transceiver may receive optical signals of varying powers, the fiber-optic transceiver comprising:

an avalanche photodiode comprising:

a gain layer;

an absorption layer; and

a field control layer disposed between the gain layer and the absorption layer, the field control layer having a doping thickness product that determines a dynamic range and is a product of a density of a dopant and a thickness of the field control layer;

a power supply that supplies a range of bias voltages to the avalanche photodiode, wherein the doping thickness product of the field control layer causes the avalanche photodiode to operate in an avalanche region when biased by a bias voltage in the range of bias voltages and wherein lowering the doping

Art Unit: 2878

thickness product lowers a punch-through voltage and raises a breakdown voltage to increase the dynamic range; a relation between the doping thickness product and an avalanche photodiode punch through voltage, breakdown voltage and dynamic range is such that for a first doping thickness product that is less than a second doping thickness product:

Page 3

a punch through voltage associated with the first doping thickness

product is relatively lower than a punch through voltage associated with

the second doping thickness product;

a breakdown voltage associated with the first doping thickness product is relatively greater than a breakdown voltage associated with the second doping thickness product; and

a dynamic range associated with the first doping thickness product
is relatively greater than a dynamic range associated with the second
doping thickness product; and

a feedback mechanism that controls the bias voltage in response to the current through the avalanche photodiode.

Claim 21 should read:

21. A fiber-optic transceiver for use in optical communications where the fiber-optic transceiver may receive optical signals of varying powers, the fiber-optic transceiver comprising:

an avalanche photodiode comprising:

a gain layer;

an absorption layer; and

Art Unit: 2878

a field control layer disposed between the gain layer and the absorption

layer, the field control layer having a doping thickness product that determines a

dynamic range and is a product of a density of a dopant and a thickness of the

field control layer;

a power supply that supplies a range of bias voltages to the avalanche

photodiode, wherein the doping thickness product of the field control layer

causes the avalanche photodiode to operate in an avalanche region when

biased by a bias voltage in the range of bias voltages such that adjusting the

doping thickness product adjusts a punch-through voltage and a breakdown

voltage to cause an adjustment in the dynamic range or a peak sensitivity and a

variation in the doping thickness product corresponds with a variation in a punch

through voltage and in a breakdown voltage, and the variation in the punch

through voltage and the breakdown voltage corresponding with a variation in the

dynamic range or in a peak sensitivity; and

a feedback mechanism that controls the bias voltage in response to the current through

the avalanche photodiode.

Conclusion

Allowable Subject Matter

Claims 1-6, 8-17 and 19-22 are allowed.

The following is an examiner's statement of reasons for allowance:

The prior art fails to teach an optical receiver and its method steps, among other

features, comprising: an avalanche comprising: a gain layer; an absorption layer; and a

field control layer, having a doping thickness product that determines a dynamic range

and is a product of a density of a dopant and a thickness of the field control layer,

Art Unit: 2878

disposed in between the gain layer and the absorption layer; a power supply for supplying a range of bias voltages to the avalanche photodiode wherein the doping thickness product of the field control layer causes the avalanche photodiode to operate in an avalanche region when biased by the range of bias voltages and a relation between the doping thickness product and an avalanche photodiode punch through voltage, breakdown voltage and dynamic range is that for a first doping thickness product that is less than a second doping product thickness product: a punch through voltage, a breakdown voltage and a dynamic range associated with the first doping thickness product are lower than a punch through voltage, greater than a breakdown voltage and greater than a dynamic range associated with the second doping thickness product respectively; and a feedback mechanism for controlling the bais voltage in response to a current through the avalanche photodiode.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tony Lu whose telephone number is 5712728448. The examiner can normally be reached on M-F 9:00am- 6:00pm.

Art Unit: 2878

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Georgia Epps can be reached on 5712722328. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Supervisory Patent Examiner Technology Center 2800

Page 6